

Article



High-Temperature Dielectric and Microwave Absorption Property of Atmospheric Plasma Sprayed Al₂O₃-MoSi₂-Cu Composite Coating

Cheng Gao ^{1,2}, Yangsheng Jiang ², Dayong Cai ^{1,*}, Jinyong Xu ² and Jia Ding ²

- ¹ College of Materials Science and Engineering, Yanshan University, No. 438 West Hebei Avenue, Qinhuangdao 066004, China; cgao1982@126.com
- ² School of Mechanical and Electrical Engineering, Guilin University of Electronic Technology, No. 1 of Jinji Road, Guilin 541004, China; bobi6658@hotmail.com (Y.J.); xujinyong62@163.com (J.X.); djguet@126.com (J.D.)
 - Correspondence: cdy@ysu.edu.cn

Abstract: Al₂O₃-MoSi₂ coating has excellent high-temperature stability. On this basis, Al₂O₃-MoSi₂-Cu composite high-temperature absorbing coating was prepared by atmospheric plasma spraying method. The phase transition characteristics of Al₂O₃-MoSi₂-Cu spraying feedstock under high temperatures were analyzed by thermogravimetric test, the phase analysis of coating was performed by an in situ XRD test at different temperatures, and the microstructure of the coating was characterized by SEM. The test results of high-temperature microwave absorption performance show that, in high-temperature air atmosphere, the Cu in the coating is gradually transformed into Cu₂O by oxygen atom diffusion, and the microwave absorption performance of the coating gradually increases with the increase in temperature. The 1.7 mm-thick coating at 500 °C has the best absorbing performance with a reflection loss (RL) value of -17.96 dB and an effective absorbing bandwidth (RL < -10 dB) in X-band of 2.42 GHz. The prepared Al₂O₃-MoSi₂-Cu composite high-temperature absorbing coating takes into account the dual advantages of high-temperature stability and high-temperature absorbing properties.

Keywords: atmospheric plasma spraying; thermal analysis; absorbing coating; Al₂O₃-MoSi₂-Cu

1. Introduction

With the rapid development of radar detection technology, absorbing materials have attracted more and more attention, especially high-temperature absorbing materials. The commonly used dielectric materials include Ti_3SiC_2 [1], SiC_f [2], and Al_2O_3 -TiC [3], and the magnetic materials include Fe₃Si [4], Cr_2AlB_2 [5], Fe@MoS₂ [6], etc. The absorbing materials include SiCN(CNTs) [7] and SiCO@BN [8], and the absorbing coatings include $La_{0.6}SrFeO_3$ - $\delta/MgAl_2O_4$ [9], TiC- $Al_2O_3/Silica$ [10], etc. There are many technical methods for preparing absorbing materials or absorbing coatings, among which the preparation of absorbing coatings by plasma spraying has good process convenience and practicability. In this study Al_2O_3 , $MoSi_2$, and Cu powders were used to prepare high-temperature absorbing coating by air plasma spraying.

MoSi₂ is often used as spraying feedstock for plasma spraying, which has good oxidation resistance, high-temperature resistance, wear resistance, and good dielectric properties [11,12], and is widely used in high-temperature oxidation resistant materials and coatings. Al₂O₃ has the advantages of high hardness and high melting point, which is commonly used in the production of high-temperature resistant materials; after fully mixing with MoSi₂, the high-temperature stability of MoSi₂ can be enhanced. Yan et al. [13] prepared Mo coatings and MoSi₂-Mo coatings using a plasma spraying method. The results showed that the MoSi₂ composition could improve the micro hardness and wear resistance of the coatings. Hou et al. [14] mixed MoSi₂ with different at% Al and prepared at% Al



Citation: Gao, C.; Jiang, Y.; Cai, D.; Xu, J.; Ding, J. High-Temperature Dielectric and Microwave Absorption Property of Atmospheric Plasma Sprayed Al₂O₃-MoSi₂-Cu Composite Coating. *Coatings* **2021**, *11*, 1029. https://doi.org/10.3390/coatings11091029

Academic Editor: Devis Bellucci

Received: 2 August 2021 Accepted: 25 August 2021 Published: 27 August 2021

Publisher's Note: MDPI stays neutral with regard to jurisdictional claims in published maps and institutional affiliations.



Copyright: © 2021 by the authors. Licensee MDPI, Basel, Switzerland. This article is an open access article distributed under the terms and conditions of the Creative Commons Attribution (CC BY) license (https:// creativecommons.org/licenses/by/ 4.0/). coating on a Ni-based superalloy by means of electrothermal explosive high-speed spraying. The oxidation resistance of the coating in the air at 1100 °C was studied. The results showed that the addition of Al to MoSi₂ could effectively improve the oxidation resistance of the coating. Huang et al. [15] prepared Al₂O₃/MoSi₂ coating by a brushing method and found that, when the content of MoSi₂ was 20%, the surface of the Al₂O₃/MoSi₂ coating remained intact after 25 thermal shock cycles. The results showed that the content of MoSi₂ had an effect on the high-temperature resistance of Al₂O₃/MoSi₂ coating. Huo et al. [16] used a plasma spraying method and flame spraying method to spray MoSi₂-Al₂O₃ powder on the surface of 310S stainless steel. After a 1200 °C high-temperature oxidation test, the coating prepared by a flame spraying process appeared powdered and peeled off, while the quality of the coating prepared by plasma spraying process was intact.

Cu has excellent electrical conductivity and wear resistance, but the dielectric loss performance of Cu is not obvious when it is used as a wave absorbent alone. Singh et al. [17] mixed Cu with different mass fraction into SiC by ball milling and designed a double-layer absorbing coating by genetic algorithm. The minimum reflection loss of the coating with a thickness of 1.67 mm in X-band reached -32.16 dB, and the absorption bandwidth (RL < -10 dB) was 2.35 GHz. Yang et al. [18] synthesized Cu-based MOF composites through Cu₂O@NPC and found that the content of Cu₂O can change the dielectric constant of the coating, thus obtaining a broadband absorbing material. The absorbing bandwidth (RL < -10 dB) of the coating with a thickness of 1.85 mm can reach 7.3 GHz, and the minimum reflection loss can reach -31.1 dB at 5.6 GHz. Gao et al. [19] prepared Cu₂O/MWCNT hybrid materials by precipitation method. The hybrid materials have excellent microwave absorption properties. When the coating thickness is 1.5 mm, the minimum reflection loss of the coating the coating thickness is 1.5 mm, the minimum reflection loss of the coating the coating thickness is 1.5 mm, the minimum reflection loss of the coating thickness is 1.6 Hz test frequency.

In this study, Al_2O_3 , $MoSi_2$, and Cu powders were used to prepare high-temperature microwave absorbing coatings. Both Al_2O_3 and $MoSi_2$ have excellent high-temperature resistance, and Cu has good electrical conductivity. However, the preparation of high-temperature absorbing coatings with high-temperature resistance by mixing Al_2O_3 , $MoSi_2$, and Cu is rarely studied. In this study, Cu was the coating inner and surface. Therefore, Cu can be oxidized to different degrees in a high-temperature environment of 500 °C; the Cu transforms to Cu₂O in high temperatures, which will improve the absorbing performance of the coating. The high-temperature resistance of the two spray feedstocks was compared. The microstructure and phase composition of Al_2O_3 -MoSi₂-Cu coating were studied, and the process of Cu transforming into Cu₂O, the key component, was analyzed at different temperatures The polarization phenomenon of the coating. With the increase in temperature further enhances the dielectric loss ability of the coating. With the continuous increase in Cu₂O in the coating, the microwave absorbing performance of the coating is gradually enhanced, especially in the high-temperature environment.

2. Materials and Methods

This experiment uses atmospheric plasma spraying equipment (SX-80, GuangZong Sanxin Company, Guangzhou, China). The Al_2O_3 -MoSi₂-Cu coating was prepared by plasma spraying method, and the sprayed coating was cut into rectangular samples for testing dielectric properties in X-band. The oxidation reaction of spraying feedstock in air atmosphere was tested by thermal analyzer (TGA, TGA400, PerkinElmer, Waltham, MA, USA), the microstructure of the coating surface was observed by scanning electron microscopy (SEM, Quanta 450 FEG, FEI Company, Hillsboro, OR, USA), and the phase analysis of the coating was characterized by operando-XRD (XRD, D8-Advance, Bruker, Bremen, Germany, Cu–K α radiation). The dielectric constant of the coating between 25 and 500 °C was measured by a vector network analyzer (Agilent E8363B PNA, Santa Clara, CA, USA).

2.1. Preparation of Spraying Feedstock

Al₂O₃, MoSi₂, and Cu powder were evenly mixed in the experiment. The particle size of Al₂O₃ powder was 30 to 60 µm, and it was produced by Shanghai Xiangtian Nano Co., Ltd. (Shanghai, China); the shape was spherical and the surface was wavy. The particle size of MoSi₂ powder was from 15 to 40 µm, and it was produced by Shanghai Naio Nano Co., Ltd. (Shanghai, China). The shape of MoSi₂ powder particles was irregular flocculent and there were small holes on the surface. The particle size of Cu ranged from 10 to 30 µm, and it was produced by Shanghai Naio Nano Co., Ltd. (Shanghai, China); the shape was ellipsoidal and the surface was smooth. Al₂O₃ powder, MoSi₂ powder, and Cu powder were mixed by planetary ball mill and ground at 300 r/min for 4 h. At the same time, alcohol was added in the process of ball milling to make three kinds of mixed particles, stirred evenly. The Al₂O₃-MoSi₂-Cu mixed powder (70 wt% Al₂O₃ + 15 wt% MoSi₂ + 15 wt% Cu) obtained by ball milling was dried by a dryer and ground by bowl; the prepared spray feedstock had excellent fluidity. SEM micrographs of Al₂O₃-MoSi₂-Cu mixed powders are shown in Figure 1.



Figure 1. SEM micrographs of Al₂O₃-MoSi₂-Cu mix powders: (**a**) the original powders; (**b**) ball milling for 4 h after spray feedstock.

2.2. Plasma Spraying Experiment

The Al₂O₃-MoSi₂-Cu coating was prepared by plasma spraying method. The substrate needs to be pretreated, including sand blasting and oil removal; these two processes can make the substrate reach the surface conditions required by plasma spraying on the substrate. Finally, Al₂O₃-MoSi₂-Cu mixed powder is sprayed on the surface of the substrate. In the process of atmospheric plasma spraying, the main gas is Ar, and the secondary gas is H₂. Ar as inert gas has good protection for spraying feedstock. H₂ can be used as a secondary gas to reduce gas, so adding H₂ can effectively prevent Cu and MoSi₂ from being oxidized. The plasma spraying parameters are shown in Table 1.

Table 1. Atmosphere plasma spraying parameter.

Parameters	Value	
Arc Current (A)	400	
Arc Voltage (V)	30	
Primary gas (Ar) flow rate (L/h)	1800	
Secondary gas (H_2) rate (L/h)	10	
Spray distance (mm)	85	
Powder carrier gas (Ar) flow rate (L/h)	200	
Powder feed rate (g/min)	20	

2.3. Micromorphology of Coating

SEM micrographs of Al_2O_3 -MoSi₂-Cu mixed coatings are shown in Figure 2. Al_2O_3 -MoSi₂-Cu powder, by plasma spraying process, formed a coating on the surface of the substrate. It can be seen from Figure 2a that there are micro holes on the surface of the coating, which are unavoidable during plasma spraying. Additionally, the existence of reasonable porosity can enhance the heat dissipation capacity of the coating. From Figure 2b, it can be found that there are Al_2O_3 , $MoSi_2$, and Cu particles on the irregular surface of the coating, and the three particles are uniformly distributed on the surface of the coating, forming an Al_2O_3 -MoSi₂-Cu mixed coating.





2.4. Properties of the Coating

The microwave absorbing properties of the Al₂O₃-MoSi₂-Cu mixed coating at high temperatures were tested by a Agilent E8363B PNA series vector network analyzer. The waveguide method is used in the X-band test, and the coating needs to be cut into a standard size of $22.9 \times 10.2 \times 2 \text{ mm}^3$. The coating needs to be kept warm for two hours before testing, and then the coating that meets the test specifications is tested by a vector network analyzer. The test temperature is 25–500 °C, and the test frequency is 8.2–12.4 GHz (X-band). The dielectric constant of Al₂O₃-MoSi₂-Cu mixed coating can be expressed as $\varepsilon_r = \varepsilon' - j\varepsilon''$.

The reflection loss of Al₂O₃-MoSi₂-Cu mixed coating can be calculated by Formula (1) [20] and Formula (2) [21].

$$R = 20 \lg \left| \frac{Z_{in} - 1}{Z_{in} + 1} \right| \tag{1}$$

$$Z_{in} = \sqrt{\frac{\mu_{\rm r}}{\varepsilon_{\rm r}}} \tanh(j \frac{2\pi f d}{c} \sqrt{\mu_{\rm r}} \varepsilon_{\rm r})$$
⁽²⁾

In the formula, Z_{in} is the input impedance, f is the frequency of the electromagnetic wave, d is the thickness of the coating, and c is the speed of light in a vacuum. Because Al₂O₃-MoSi₂-Cu mixed coating is dielectric material at high temperature, the value of μ_r is 1.

3. Results and Discussion

3.1. Phase Analysis of the Coating

The transformation process of the Al₂O₃-MoSi₂-Cu coating from Cu to Cu₂O at different temperatures was analyzed by XRD, and the compounds produced by the Al₂O₃-MoSi₂-Cu coating at different temperatures were determined. Figure 3 shows the XRD patterns at different temperatures, and the range of 20 is 20–80°. It can be seen from Figure 3 that the diffraction peak of Cu₂O is not obvious at room temperature (25 °C), and only a weak peak appears at 42°. This is because a small quantity of Cu₂O is produced by high-temperature oxidation of Cu during plasma spraying. With the temperature reaching 500 °C, the characteristic peak of Cu₂O becomes sharp at 36° and gradually highlights at approximately 61°, indicating that Cu gradually transforms into Cu₂O with the increase in temperature.



Figure 3. XRD patterns of Al₂O₃-MoSi₂-Cu coatings at different temperatures.

Figure 4 is a locally enlarged XRD pattern in Figure 3, as shown in Figure 3, when the temperature rises from 25 to 500 °C. No characteristic peak appears at 25 °C; when the temperature rises to 300 °C, a single peak gradually bulges and becomes sharp at 500 °C. This shows that Al_2O_3 -MoSi₂-Cu coating will produce new compounds with the increase in temperature of air atmosphere. Through the comparison of three temperatures, it can clearly be observed that Cu in the coating will gradually transform into Cu₂O.



Figure 4. Figure 3 locally enlarged graphs in the range of 2θ from 35° to 38° .

3.2. Thermal Analysis

Thermogravimetric analysis of Al₂O₃-MoSi₂ powder and Al₂O₃-MoSi₂-Cu powder was performed by thermal analyzer, with a test temperature from room temperature $(25 \,^{\circ}\text{C})$ to 1000 $^{\circ}\text{C}$ and a heating rate of 10 degrees Celsius per minute. MoSi₂ and Al₂O₃ are selected because MoSi₂ has good high-temperature resistance and is commonly used in high-temperature structures in the aerospace field. However, with the increase in temperature, the "pesting" phenomenon [22] usually occurs at 400 to 600 °C, and the appropriate mixing of Al_2O_3 in $MoSi_2$ can effectively prevent the $MoSi_2$ occurrence of pulverizing in the coating surface. In Figure 5, the black curves show the weight change trend of Al₂O₃-MoSi₂ powder during heating. It can be seen that Al₂O₃-MoSi₂ powder increases with temperature, and the weight of powder remains stable below 500 °C. When Al₂O₃-MoSi₂ powder rises from 500 to 800 °C, the mass of powder increases by 1.36%. When the temperature of Al₂O₃-MoSi₂ powder changes from 800 to 1000 $^{\circ}$ C, it goes through a process of decrease and increase, and, finally, remains at approximately 100%. It can be seen from the thermogravimetric curve of Al₂O₃-MoSi₂ powder that there is no weight decrease phenomenon in the Al_2O_3 -MoSi₂ powder. The quality of the Al_2O_3 -MoSi₂ powder did not drop sharply, but remained stable. This shows that the content of Al₂O₃-MoSi₂ powder is reasonable and has high-temperature stability. The red curve in Figure 5 is the weight change trend of Al_2O_3 -MoSi₂-Cu powder during the heating process. It can be found that, due to the addition of Cu, when Al₂O₃-MoSi₂-Cu powder is heated from 400 to 1000 °C, the mass of Al₂O₃-MoSi₂-Cu powder increases gradually. When the temperature reaches 1000 °C, the mass increases by 10%, relative to the original weight, because different compounds result from oxidation with the increase in temperature of air atmosphere, which increase the quality of Al₂O₃-MoSi₂-Cu powder. Al₂O₃ phase transformation occurs in different temperature environments. According to the report, Al₂O₃ was transformed to γ -Al₂O₃ [23] at a temperature of 500 °C; when the temperature reaches 900 °C, γ -Al₂O₃ will continue to transform in to θ -Al₂O₃ [23]. MoSi₂ will be transformed to Mo₅Si₃ in a high-temperature environment, and SiO_2 will be formed [24]. Cu was oxidized to Cu_2O_2 , and Cu₂O further oxidized to CuO in a high-temperature environment with sufficient air [25]. Chemical reactions and phase transitions of Al₂O₃-MoSi₂ and Al₂O₃-MoSi₂-Cu powders at different temperatures can be expressed by chemical Formulaes (3)–(7).

$$Al_2O_3 \xrightarrow{500^{\circ}C} \gamma - Al_2O_3 \tag{3}$$

$$Al_2O_3 \xrightarrow{900^\circ C} \theta - Al_2O_3$$
 (4)

$$MoSi_2 + 7O_2 \xrightarrow{\Delta} Mo_5Si_3 + 7SiO_2$$
 (5)

$$4Cu + O_2 \xrightarrow{\Delta} 2Cu_2O \tag{6}$$

$$2Cu_2O + O_2 \xrightarrow{\Delta} 4CuO \tag{7}$$



Figure 5. Thermogravimetric curve of Al₂O₃-MoSi₂ powder and Al₂O₃-MoSi₂-Cu powder.

The thermogravimetric curves show that Al_2O_3 -MoSi₂ powder can increase the hightemperature oxidation resistance of the material. The CuO [26] and Cu₂O formed by Cu oxidation at high temperature can improve the microwave absorption performance of the material.

3.3. Dielectric Properties of the Coating

The dielectric properties of the coating at room temperature (25 $^{\circ}$ C) to 500 $^{\circ}$ C were tested; Figure 6a shows the change of the real part of dielectric constant of Al₂O₃-MoSi₂-Cu coating with increasing microwave frequency at different temperatures. In the 8.5 GHz microwave frequency environment at 500 °C, the dielectric constant of the coating is 25.29. When the frequency increases to 12 GHz, the dielectric constant is 20.05. Figure 6b shows the change in the imaginary part of the dielectric constant of the Al₂O₃-MoSi₂-Cu coating with the increase in microwave frequency at different temperatures: at 500 °C, the imaginary part of the dielectric constant is 4.43 at 8.5 GHz microwave frequency and 5.34 at 12 GHz. Figure 6c shows that the tan δ of the Al₂O₃-MoSi₂-Cu coating increases from 0.181 at 8.5 GHz to 0.271 at 12 GHz at 500 $^{\circ}$ C. It can be seen that the loss ability of the Al₂O₃-MoSi₂-Cu coating increases with the increase in environment temperature. The dielectric constant of the coating increases with the increase in temperature, but the dielectric constant decreases with the increase in frequency at different temperatures; this phenomenon-that the dielectric constant decreases with the increase in frequency-fully conforms to the dispersion effect [27]. Figure 6e is the permittivity of the Al₂O₃-MoSi₂-Cu₂O coating by the same process. The ε' is 8.51 and the ε'' is 1.66 in the 8.5 GHz microwave frequency. The frequency increases to 12 GHz, ε' is 8.27, and ε'' is 2.12. The Al₂O₃-MoSi₂-Cu₂O coating is not affected by temperature, so the permittivity changes little.



Figure 6. Dielectric properties of Al₂O₃-MoSi₂-Cu composite coating: (a) ε' of Al₂O₃-MoSi₂-Cu composite coating; (b) ε'' of Al₂O₃-MoSi₂-Cu composite coating; (c) Tan δ of Al₂O₃-MoSi₂-Cu composite coating; (d) the Cole–Cole plot of Al₂O₃-MoSi₂-Cu composite coating with the fitting date in 500 °C; (e) permittivity of Al₂O₃-MoSi₂-Cu₂O composite coating at room temperature (25 °C).

The ε' and ε'' of Al₂O₃-MoSi₂-Cu₂O composite coating can be expressed as Formulaes (8) and (9) according to the Debye model [28].

$$\varepsilon' = \varepsilon_{\infty} + \frac{\varepsilon_{\rm s} - \varepsilon_{\infty}}{1 + \omega^2 \tau^2} \tag{8}$$

$$\varepsilon'' = \frac{(\varepsilon_{\rm s} - \varepsilon_{\infty})\omega\tau}{1 + \omega^2\tau^2} \tag{9}$$

In the equation, ε_S is static dielectric constant and ε_∞ is optical frequency dielectric constant. The Al₂O₃-MoSi₂-Cu coating permittivity change in real part and imaginary part at high temperatures can be deduced by Formulas (10) and (11) [29,30].

$$\varepsilon' = \varepsilon_{\infty} + \frac{\varepsilon_{\rm s} - \varepsilon_{\infty}}{1 + \omega^2 \tau({\rm T})^2} \tag{10}$$

$$\varepsilon'' = \varepsilon_{\infty} + \frac{(\varepsilon_{S} - \varepsilon_{\infty})\omega\tau(T)}{1 + \omega^{2}[\omega\tau(T)]^{2}} + \frac{\sigma(T)}{\omega\varepsilon_{0}}$$
(11)

In the equation, $\tau(T)$ is polarization relaxation time influenced by temperature, ε_0 is the vacuum dielectric constant, and $\sigma(T)$ is the conductivity affected by temperature

The change in ε' and ε'' can be obtained by Formulae (10) and (11). This is because the external electric field of the coating changes with the temperature. The change of polar molecules inside the coating cannot keep up with the drastic change in external electric field caused by temperature. Figure 6d is the Cole–Cole fitting plot of Al₂O₃-MoSi₂-Cu coating at 500 °C; it can be seen that there are two incomplete and irregular semicircles rather than a complete semicircle in the figure, indicating that the coating has not only Debye relaxation but also other relaxation [31] mechanisms at high temperatures. The irregular semicircles show that the Al₂O₃-MoSi₂-Cu coating has two losses at 500 °C. Al₂O₃-MoSi₂-Cu coating is made of an electrical material and is dominated by dielectric loss. The ε' and ε'' of the coating increase with the increase in temperature. A conductive network is formed by Al₂O₃ and MoSi₂ in the coating [12]. With the increase in temperature, Cu gradually transforms into Cu₂O, and the conductive network formed together with Al₂O₃-MoSi₂-Cu coating has significant dielectric properties at high temperature.

3.4. Absorbing Performance of the Coating

The absorbing properties of the coating are shown in Figure 7. Figure 7b shows that the absorption peak of Al_2O_3 -MoSi₂-Cu coating with 1.5 mm thickness is approximately 11 GHz. The absorption performance of the coating is not obvious at 25 °C. The minimum reflection loss is -3.09 dB at 11.4 GHz and -16.07 dB at 500 °C. The coating has the best absorbing property at 500 °C; it shows that Al_2O_3 -MoSi₂-Cu coating has good high-temperature absorbing properties. With the increase in temperature, the dielectric constant of the coating increases, and the absorbing bandwidth of the coating moves from high frequency to low frequency. This law conforms to Formula (12) [32].

$$f_m = \frac{c}{4d\sqrt{\varepsilon_r \mu_r}} \tag{12}$$

In the equation, *d* is the thickness of the coating, and *c* is the speed of light in vacuum.

Microwave absorbing properties of Al_2O_3 -MoSi₂-Cu coatings improved significantly from room temperature (25 °C) to 500 °C, mainly due to the transformation of Cu on the coating surface into Cu₂O in air atmosphere; Cu₂O can effectively improve the absorbing properties of materials [33]. According to Figure 3—the XRD pattern results of the coating the characteristic peak of Cu₂O became obvious at 500 °C, indicating that Cu₂O was generated. It can be seen from Figure 2 SEM micrographs that there are different sizes of pores in the coating; as the temperature rises, the air reacts with Cu on the coating surface and enters the coating from the pores to react with Cu. The reason for the formation of Cu₂O is that Cu is first transformed into Cu₂O due to insufficient oxygen during heating. There are also peaks of Cu. It is indicated that a Cu₂O/Cu mixture exists in the coating, which is due to the fact that Cu in the coating cannot react completely with air during heating in air. Comparing Figure 6a,b,e, it can be seen that, with the temperature rises, the coating surface is the site of the oxidation reaction, in the coating inner where lattice vibration occurs; as the temperature increases, the lattice vibrates with greater intensity. At the same time, high temperature causes a change in conductivity. These three reasons together lead to the dielectric constant change in the coating at high temperatures. Cu has strong conductivity, but the absorbing property of the composite coating is not obvious at room temperature, according to Figure 7c. The coating thickness is 1.7 mm, and the minimum reflection loss at 25 °C is only -4.89 dB. The minimum reflection loss decreases to -17.96 dB at 500 °C. Because Cu is transformed into Cu₂O, the conductive network is formed with Al₂O₃-MoSi₂, which enhances the absorbing loss performance of the coating.

-5

.10

-15

-20

-25

8

Reflection Loss/dB

......

9

- 100°C

400°C

11

25°C

10

(b)

300°C

Frequency/GHz

200°C

- 500°C

12

.



Figure 7. Reflection loss of the Al_2O_3 -MoSi₂-Cu composite coatings: (a) d = 1.3; (b) d = 1.5; (c) d = 1.7.

The results show that the Al_2O_3 -MoSi₂-Cu microwave absorbing coating has good high-temperature resistance and microwave absorption performance at 500 °C.

4. Conclusions

The results show that the Al₂O₃-MoSi₂-Cu coating has good microwave absorption properties at 500 °C, and the microwave absorption performance of the coating increases with the increase in temperature. Thermogravimetric analysis assisted to verify the rationality of spray feedstock match ratio and the stability of the coating in a high-temperature environment. The phase composition of the coating and the changes in the compounds at different temperatures were studied using an in situ XRD test. Finally, the dielectric properties and microwave absorbing properties of a 1.7 mm-thick coating in the range of 25 °C–500 °C were tested by a vector network analyzer. The existence of Cu/Cu₂O mixture in the coating enhances the conductivity loss of the coating. At high temperatures, Cu₂O and Al₂O₃-MoSi₂ form a conductive network, which enhances the microwave absorbing properties of the coating properties in X-band.

Author Contributions: Conceptualization, C.G. and Y.J.; methodology, C.G.; formal analysis, Y.J.; investigation, C.G.; data curation, J.D.; writing—original draft preparation, C.G. and Y.J.; writing—review and editing, D.C.; visualization, Y.J.; supervision, D.C.; project administration, J.X.; funding acquisition, J.X. All authors have read and agreed to the published version of the manuscript.

Funding: Guangxi S & T Program (No.AD18126024).

Institutional Review Board Statement: Not applicable.

Informed Consent Statement: Not applicable.

Data Availability Statement: Data are included in this article.

Conflicts of Interest: The authors declare no conflict of interest.

References

- Su, J.; Zhou, W.; Liu, Y.; Qing, Y.; Luo, F.; Zhu, D. High-Temperature Dielectric and Microwave Absorption Property of Plasma Sprayed Ti₃SiC₂/Cordierite Coatings. J. Mater. Sci. Mater. Electron. 2016, 27, 2460–2466. [CrossRef]
- Zhou, Q.; Yin, X.; Ye, F.; Tang, Z.; Mo, R.; Cheng, L. High Temperature Electromagnetic Wave Absorption Properties of SiCf/Si₃N₄ Composite Induced by Different SiC Fibers. *Ceram. Int.* 2019, 45, 6514–6522. [CrossRef]
- Shao, T.; Ma, H.; Wang, J.; Feng, M.; Yan, M.; Wang, J.; Yang, Z.; Zhou, Q.; Luo, H.; Qu, S. High Temperature Absorbing Coatings with Excellent Performance Combined Al₂O₃ and TiC Material. *J. Eur. Ceram. Soc.* 2020, 40, 2013–2019. [CrossRef]
- 4. Hou, Y.; Xiao, B.; Sun, Z.; Yang, W.; Wu, S.; Qi, S.; Wen, G.; Huang, X. High Temperature Anti-Oxidative and Tunable Wave Absorbing SiC/Fe₃Si/CNTs Composite Ceramic Derived from a Novel Polysilyacetylene. *Ceram. Int.* **2019**, *45*, 16369–16379. [CrossRef]
- 5. Zhang, H.; Zhao, B.; Xiang, H.; Dai, F.; Zhang, Z.; Zhou, Y. Electromagnetic Wave Absorbing Properties of Cr₂ AlB₂ Powders and the Effect of High-temperature Oxidation. *J. Am. Ceram. Soc.* **2021**, *104*, 2213–2224. [CrossRef]
- Pan, J.; Sun, X.; Wang, T.; Zhu, Z.; He, Y.; Xia, W.; He, J. Porous Coin-like Fe@MoSi₂ Composite with Optimized Impedance Matching for Efficient Microwave Absorption. *Appl. Surf. Sci.* 2018, 457, 271–279. [CrossRef]
- Wang, S.; Gong, H.; Zhang, Y.; Ashfaq, M.Z. Microwave Absorption Properties of Polymer-Derived SiCN (CNTs) Composite Ceramics. *Ceram. Int.* 2021, 47, 1294–1302. [CrossRef]
- 8. Hou, Y.; Yang, W.; Zhong, C.; Wu, S.; Wu, Y.; Liu, F.; Huang, X.; Wen, G. Thermostable SiCO@BN Sheets with Enhanced Electromagnetic Wave Absorption. *Chem. Eng. J.* **2019**, *378*, 122239. [CrossRef]
- Jia, H.; Zhou, W.; Nan, H.; Qing, Y.; Luo, F.; Zhu, D. High Temperature Microwave Absorbing Properties of Plasma Sprayed La0.6Sr0.4FeO₃-δ/MgAl₂O₄ Composite Ceramic Coatings. *Ceram. Int.* 2020, 46, 6168–6173. [CrossRef]
- Wang, Y.; Luo, F.; Zhou, W.; Zhu, D. Dielectric and Microwave Absorption Properties of TiC-Al2O3/Silica Coatings at High Temperature. J. Electron. Mater. 2017, 46, 5225–5231. [CrossRef]
- 11. Zhang, Y.; Li, Y.; Bai, C. Microstructure and Oxidation Behavior of Si–MoSi 2 Functionally Graded Coating on Mo Substrate. *Ceram. Int.* **2017**, *43*, 6250–6256. [CrossRef]
- Wu, Z.; Zhou, W.; Luo, F.; Zhu, D. Effect of MoSi2 Content on Dielectric and Mechanical Properties of MoSi₂/Al₂O₃ Composite Coatings. *Trans. Nonferrous Met. Soc. China* 2012, 22, 111–116. [CrossRef]
- Yan, J.; He, Z.; Wang, Y.; Qiu, J.; Wang, Y. Microstructure and Wear Resistance of Plasma-Sprayed Molybdenum Coating Reinforced by MoSi₂ Particles. J. Therm. Spray Tech. 2016, 25, 1322–1329. [CrossRef]
- 14. Hou, S.; Liu, Z.; Liu, D.; Li, B. Effect of Alloying with Al on Oxidation Behavior of MoSi₂ Coatings at 1100 °C. *Surf. Coat. Technol.* **2012**, 206, 4466–4470. [CrossRef]
- 15. Huang, X.; Zhang, F.; Zhao, Y.; An, X.; Yang, J. Preparation and Properties of Al₂O₃/MoSi₂ Coating on Al₂O₃ Base Porous Insulation Materials. *Fuhe Cailiao Xuebao/Acta Mater. Compos. Sin.* **2020**, *37*, 2870–2876. [CrossRef]
- Huo, D.; Li, W.-S.; Feng, L.; Hu, C.-X.; Hu, W. Effects of Spraying Process on Microstructure and Properties of MoSi₂-Al₂O₃ Coating. Surf. Technol. 2018, 47, 267–273. [CrossRef]
- 17. Singh, S.; Sinha, A.; Zunke, R.H.; Kumar, A.; Singh, D. Double Layer Microwave Absorber Based on Cu Dispersed SiC Composites. *Adv. Powder Technol.* **2018**, *29*, 2019–2026. [CrossRef]
- Yang, H.; Zhang, X.; Xiong, Z.; Shen, Z.; Liu, C.; Xie, Y. Cu₂O@nanoporous Carbon Composites Derived from Cu-Based MOFs with Ultrabroad-Bandwidth Electromagnetic Wave Absorbing Performance. *Ceram. Int.* 2021, 47, 2155–2164. [CrossRef]
- 19. Gao, S.; Xing, H.; Li, Y.; Wang, H. Synthesis of Cu₂O/Multi-Walled Carbon Nanotube Hybrid Material and Its Microwave Absorption Performance. *Res. Chem. Intermed.* **2018**, *44*, 3425–3435. [CrossRef]
- 20. Bi, S.; Su, X.; Li, J.; Hou, G.; Liu, Z.; Zhong, C.; Hou, Z. High-Temperature Dielectric Properties and Microwave Absorption Abilities of Bi1–xMgxFeO₃ Nanoparticles. *Ceram. Int.* **2017**, *43*, 11815–11819. [CrossRef]
- 21. Sun, Y.; Sun, Y. Strong and Thermostable Boron-Containing Phenolic Resin-Derived Carbon Modified Three-Dimensional Needled Carbon Fiber Reinforced Silicon Oxycarbide Composites with Tunable High-Performance Microwave Absorption Properties. *Appl. Sci.* **2020**, *10*, 1924. [CrossRef]
- 22. Yakaboylu, G.A.; Yumak, T.; Sabolsky, K.; Sabolsky, E.M. Effect of High Temperature Preoxidation Treatment on the Oxidation Behavior of MoSi₂ and WSi₂–Al₂O₃ Composites. *J. Alloys Compd.* **2020**, *816*, 152499. [CrossRef]

- Taghi-Ramezani, S.; Valefi, Z.; Mirjani, M.; Ghasemi, R. The Influence of Pyrolysing Al₂O₃ Precursor on the High Temperature Properties of the YSZ-Al₂O₃ Composite Coating. *Surf. Eng.* 2020, 1–11. [CrossRef]
- 24. Cai, Z.; Liu, S.; Xiao, L.; Fang, Z.; Li, W.; Zhang, B. Oxidation Behavior and Microstructural Evolution of a Slurry Sintered Si-Mo Coating on Mo Alloy at 1650 °C. *Surf. Coat. Technol.* **2017**, *324*, 182–189. [CrossRef]
- 25. Serrà, A.; Gómez, E.; Michler, J.; Philippe, L. Facile Cost-Effective Fabrication of Cu@Cu₂O@CuO–Microalgae Photocatalyst with Enhanced Visible Light Degradation of Tetracycline. *Chem. Eng. J.* **2021**, *413*, 127477. [CrossRef]
- 26. Ma, J.; Zhang, X.; Liu, W.; Ji, G. Direct Synthesis of MOF-Derived Nanoporous CuO/Carbon Composites for High Impedance Matching and Advanced Microwave Absorption. *J. Mater. Chem. C* 2016, *4*, 11419–11426. [CrossRef]
- 27. Benzerga, R.; Badard, M.; Méjean, C.; El Assal, A.; Le Paven, C.; Sharaiha, A. Carbon Fibers Loaded Composites for Microwave Absorbing Application: Effect of Fiber Length and Dispersion Process on Dielectric Properties. *J. Electron. Mater.* **2020**, *49*, 2999–3008. [CrossRef]
- 28. Debye, P. Polar Moecules; The Chemical Catalogue Company: New York, NY, USA, 1929.
- 29. Song, W.; Cao, M.; Hou, Z.; Yuan, J.; Fang, X. High-Temperature Microwave Absorption and Evolutionary Behavior of Multiwalled Carbon Nanotube Nanocomposite. *Scr. Mater.* **2009**, *61*, 201–204. [CrossRef]
- Cao, M.-S.; Song, W.-L.; Hou, Z.-L.; Wen, B.; Yuan, J. The Effects of Temperature and Frequency on the Dielectric Properties, Electromagnetic Interference Shielding and Microwave-Absorption of Short Carbon Fiber/Silica Composites. *Carbon* 2010, 48, 788–796. [CrossRef]
- 31. Grosse, C. A Program for the Fitting of Debye, Cole–Cole, Cole–Davidson, and Havriliak–Negami Dispersions to Dielectric Data. *J. Colloid Interface Sci.* **2014**, *419*, 102–106. [CrossRef]
- 32. Gao, H.; Luo, F.; Wen, Q.; Jia, H.; Zhou, W.; Zhu, D. Enhanced High-temperature Dielectric and Microwave Absorption Properties of SiC Fiber-reinforced Oxide Matrix Composites. *J. Appl. Polym. Sci.* 2019, 136, 47097. [CrossRef]
- Zong, M.; Huang, Y.; Wu, H.; Zhao, Y.; Liu, P.; Wang, L. Facile Preparation of RGO/Cu₂O/Cu Composite and Its Excellent Microwave Absorption Properties. *Mater. Lett.* 2013, 109, 112–115. [CrossRef]